

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IXTP200N075T

				v
R⊳s(• Fully cl • 100% a • Minimu	drain-source on-resistance: fon) $\leq 5.0 m\Omega @V_{GS}=10V$ haracterized avalanche voltage and co avalanche tested um Lot-to-Lot variations for robust dev nance and reliable operation			pin 1, Gate 1 2 3 1 2 2 1 2 2 1 2 3 2, Drain 3, Source TO-220C package
• DC/DC	; Converters			10 VE1 00
 DC/DC Converters High Current Switching Applications ABSOLUTE MAXIMUM RATINGS(Ta=25°C) SYMBOL PARAMETER VALUE UNIT V_{DSS} Drain-Source Voltage 75 V 				
SYMBOL	PARAMETER	VALUE	UNIT	φ
V _{DSS}	Drain-Source Voltage	75	V	
V _{GS}	Gate-Source Voltage	±20	V	
ID	Drain Current-Continuous	200	A	
I _{DM}	Drain Current-Single Pulsed	540	A	
PD	Total Dissipation @Tc=25°C	430	W	DIM MIN MAX A 15.50 15.90 B 9.90 10.20
Tj	Operating Junction Temperature	-55~175	°C	C 4.20 4.50 D 0.70 0.90
T _{stg}	Storage Temperature	-55~175	°C	F 3.40 3.70 G 4.98 5.18 H 2.68 2.90
• THERM	MAL CHARACTERISTICS			J 0.44 0.60 K 13.00 13.40 L 1.10 1.45
				Q 2.70 2.90

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SYMBOL	SYMBOL PARAMETER		UNIT	
R _{th(j-c)}	Junction-to-case thermal resistance	0.35	°C/W	

R

U

V

2.30

1.29

6.45 8.66 2.70

1.35

6.65

8.86



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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; ID = 250 μ A	75		V
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} =V _{GS} ; ID = 250 μ A	2.0	4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D = 25A		5.0	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V		±200	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = V _{DSS} ; V _{GS} = 0V	5		μA
		V _{DS} = V _{DSS} ; V _{GS} = 0V;T _J = 150℃		250	
V_{SD}	Diode forward voltage	I _F = 25A; V _{GS} = 0V		1.0	V

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